

IEEE CLEDO BRUNETTI AWARD

RECIPIENTS

- 2018- SIEGFRIED SELBERHERR
Professor, Vienna University of
Technology, Institute for
Microelectronics, Vienna, Austria
- “For pioneering contributions to Technology
Computer Aided Design.”
- 2017- GUIDO GROESENEKEN
Professor, Catholic University of
Leuven, and Fellow, IMEC, Leuven,
Belgium
- “For contributions to the characterization
and understanding of the reliability physics
of advanced MOSFET nanodevices.”
- 2016 – AKIRA TORIUMI
Professor, The University of Tokyo,
Tokyo, Japan
- “For contributions to CMOS device design
from materials engineering to device
physics.”
- 2015 - HIROSHI IWAI
Professor, Tokyo Institute of
Technology, Yokohama, Kanagawa,
Japan
- “For contributions to the scaling of CMOS
devices.”
- 2014 – MARTIN VAN DEN BRINK
Vice President, ASML,
Veldhoven, The Netherlands
- “For designing new lithography tool
concepts and bringing these to the market,
enabling micrometer to nanometer
imaging.”
- 2013 – GIORGIO BACCARANI
Full Professor, University of
Bologna, Bologna, Italy
- “For contributions to scaling theory and
modeling of metal oxide semiconductor
(MOS) devices.”
- 2012 - YAN BORODOVSKY
Intel Senior Fellow, Director of
Advanced Lithography, Intel
Corporation, Hillsboro, OR, USA
- AND
- SAM SIVAKUMAR
Intel Fellow, Director of
Lithography, Intel Corporation,
Hillsboro, OR, USA
- 2011 – MASSIMO V. FISCHETTI
Professor, University of
Massachusetts, Amherst, MA, USA
- AND
- DAVID J. FRANK
Research Staff Member, IBM T. J.
Watson Research Center,
- “For contributions to the fundamental
understanding of the physics, design and
scaling of nanosized electronic devices.”

IEEE CLEDO BRUNETTI AWARD
RECIPIENTS

- Yorktown Heights, NY, USA
AND
STEVEN E. LAUX
Research Staff Member, IBM T. J.
Watson Research Center,
Yorktown Heights, NY, USA
- 2010 – GHAVAM SHAHIDI
IBM Fellow Director of Silicon Tech
IBM TJ Watson Research Ctr
Yorktown Heights, NY, USA
"For contributions to and leadership in the development of silicon-on-insulator CMOS technology."
- 2009 – BURN JENG LIN
Senior Director of Micropatterning
Division, TSMC, Ltd. Hsin-Chu,
Taiwan
"For contributions to immersion lithography for the manufacture of integrated circuit devices."
- 2008 – MICHEL BRUEL
Deputy Director of CEA-LETI,
Director of Research, CEA, Cedex,
France
"For inventing Smart Cut™ layer transfer technology that enabled widespread adoption of SOI for CMOS circuits."
- 2007 – SANDIP TIWARI
Professor, Electrical and Computer
Engineering, Cornell University
Ithaca, NY
"For pioneering contributions to nano-crystal memories and to quantum effect devices."
- 2006 – SUSUMU NAMBA
Professor, Nagasaki Institute of
Applied Science
Nagasaki, Japan
"For contributions to ion-beam and optical technologies for application to semiconductor devices."
- 2005 – WILLIAM G. OLDHAM
Professor Emeritus, University of
California, Berkeley
Berkeley, CA
"For pioneering contributions to lithographic engineering and to high-density isolation technology."
- 2004 – STEPHEN Y. CHOU
Professor, Department of Electrical
Engineering
Princeton University
Princeton, NJ
"For the invention and development of tools for nanoscale patterning, especially nanoimprint lithography, and for the scaling of devices into new physical regimes."
- 2003 - ANDREW R. NEUREUTHER
Professor, EECS, University of
California, Berkeley, CA
"For pioneering contributions to modeling and simulation of the lithographic materials, processes, and tools used in microelectronics manufacturing."

IEEE CLEDO BRUNETTI AWARD
RECIPIENTS

- 2002 – MARK LUNDSTROM
SUPRIYO DATTA
Purdue University, West Lafayette,
IN
- 2001 – R. FABIAN W. PEASE
Stanford University
Stanford, CA
- 2000 - ROBERT E. FONTANA
IBM Almaden Research Center
San Jose, CA
- 1999 - DAVID K. FERRY
Arizona State Univ., Tempe, AZ
- 1998 - ROGER T. HOWE
RICHARD S. MULLER
University of California, Berkeley,
CA
- 1997 - DIETER P. KERN
GEORGE A. SAI-HALASZ
MATTHEW R. WORDEMAN
IBM Research, Yorktown Heights,
NY
- 1996 - MITSUMASA KOYANAGI
Tohoku Univ Intell Sys Lab
Sendai, Japan
- 1995 - HENRY I. SMITH
MIT, Cambridge, MA
- 1994 - EIJI TAKEDA
Hitachi Ltd.
Tokyo, Japan
- 1993 - TAKAFUMI NAMBU
MITSURU IDA
KAMON YOSHIYUKI
SONY Corporation, Tokyo, Japan

IEEE CLEDO BRUNETTI AWARD
RECIPIENTS

- | | |
|--|--|
| 1992 - DAVID A. THOMPSON
IBM Corp.
San Jose, CA | "For pioneering work in miniature magnetic devices for data storage, including the invention, design and development of thin-film and magnetoresistive recording heads." |
| 1991 - HIDEO SUNAMI
Hitachi, Ltd., Tokyo, Japan | "For contributions in the invention and development of the trench capacitor DRAM cell." |
| 1990 - ELSE KOOI
Philips Research Labs.
Sunnyvale, CA | "For invention and development of the process for localized oxidation of silicon using a silicon nitride mask, which enabled greatly reduced dimensions in VLSI circuits." |
| 1989 - SHUN-ICHI IWASAKI
Tohoku University, Sendai, Japan | "For contributions to the miniaturization of magnetic recording systems." |
| 1988 - IRVING AMES - IBM Corp., NY
FRANCOIS M. d'HEURLE
RICHARD E. HORSTMANN | "For the invention of electromigration-resistant copper-doped aluminum metallurgy." |
| 1987 - MICHAEL HATZAKIS
IBM Corp., Yorktown Heights, NY | "For fundamental contributions to the patterning techniques of submicron electron devices." |
| 1986 - RICHARD M. WHITE
Univ of California, Berkeley, CA | "For invention of surface acoustic wave electronic devices for signal processing applications." |
| 1985 - ALEC N. BROERS
IBM Corporation
Hopewell Junction, NY | "For leadership and pioneering contributions to the technology and applications of electron beams to fine line lithography." |
| 1984 - HARRY W. RUBINSTEIN
Sprague Electric Co.
Grafton, Wisconsin | "For early key contributions to the development of printed components and conductors on a common insulating substrate." |
| 1983 - ABE OFFNER
Perkin-Elmer Corp.
Wilton, CT | "For the invention and design of the optics which made possible the projection lithography systems that were key to advancing integrated circuit manufacture." |
| 1982 - ROBERT H. DENNARD
IBM Corp. | "For the invention of the one-transistor dynamic random access memory cell and |

IEEE CLEDO BRUNETTI AWARD
RECIPIENTS

- | | |
|---|--|
| Yorktown Heights, NY | for contributions to scaling of MOS devices." |
| 1981 - DONALD R. HERRIOTT
Bell Labs.
Murray Hill, NJ | "For key contributions to the development of a practical electron beam system for fabrication of integrated circuit masks and to other aspects of microlithography." |
| 1980 - MARCIAN E. HOFF, JR.
INTEL Corp.
Santa Clara, CA | "For the conception and development of the microprocessor." |
| 1979 - GEOFFREY W. A. DUMMER
Worcestershire, England
AND
PHILIP J. FRANKLIN
GSA, Federal Supply Service
Washington, DC | "For contributions to materials development and fabrication techniques for miniature passive electronic components and assemblies." |
| 1978 - JACK S. KILBY
Texas Instrument, Dallas, TX
ROBERT N. NOYCE
Intel Corporation, Santa Clara, CA | "For contributions to miniaturization through inventions and the development of integrated circuits." |